MIC2033

High-Accuracy, High-Side, Fixed Current-Limit Power Switch

Features

- ±5% Current-Limit Accuracy
- Input Supply Range from 2.5V to 5.5V
- Low Quiescent Current: 100 µA Typical (Switch ON)
- 75 mΩ Typical $R_{DS(ON)}$ at 5V
- Current-Limit Options: 0.5A, 0.8A, 1A, and 1.2A
- Soft-Start Control via an External Capacitor
- Undervoltage Lockout (UVLO)
- Fast Response Time (10 µs) to Short-Circuit Loads
- Fault Status Output Flag
- Logic Controlled Enable (Active-High, Active-Low)
- Thermal Shutdown
- Pin Compatible with MIC2005
- 6-Pin 2 mm x 2 mm Thin DFN and 6-Pin SOT-23 Packages
- Junction Temperature Range from –40°C to +125°C

Applications

- USB Peripherals and USB 2.0/3.0-Compatible
- DTV/STB
- Notebooks and Consumer Electronics
- General Purpose Power Distribution

General Description

The MIC2033 is a high-side MOSFET power distribution switch that provides increased system reliability, utilizing 5% current-limit accuracy.

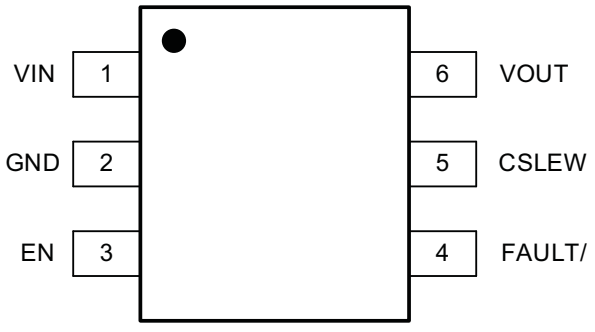
The MIC2033 has an operating input voltage range from 2.5V to 5.5V, is internally current-limited and has thermal shutdown to protect the device and system. The MIC2033 is offered with either active-high or active-low logic level enable input controls, has an open-drain fault status output flag with a built-in 32 ms delay that asserts low during over current or thermal shutdown conditions.

The MIC2033 is available in several different fixed current-limit options: 0.5A, 0.8A, 1A, and 1.2A. A capacitor-adjustable soft-start circuit minimizes inrush current in applications where high capacitive loads are used.

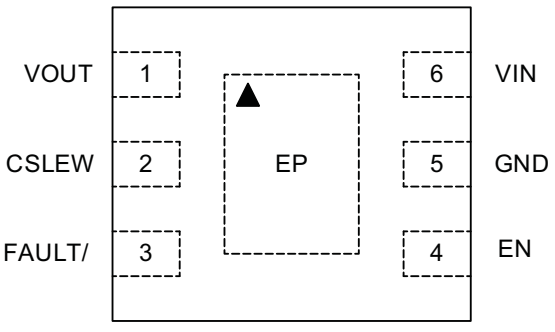
The MIC2033 is offered in both 6-pin SOT-23 and 6-pin 2 mm x 2 mm thin DFN packages. The MIC2033 has an operating junction temperature range of –40°C to +125°C.

Package Types

MIC2033
SOT-23-6 (M6)



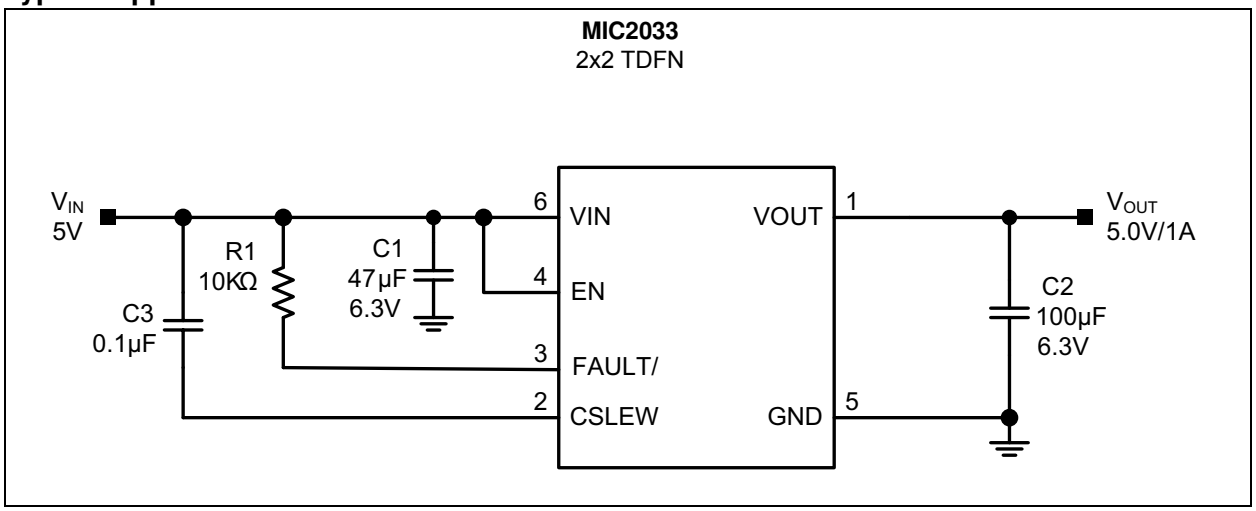
MIC2033
2x2 TDFN (MT) (Note 1)



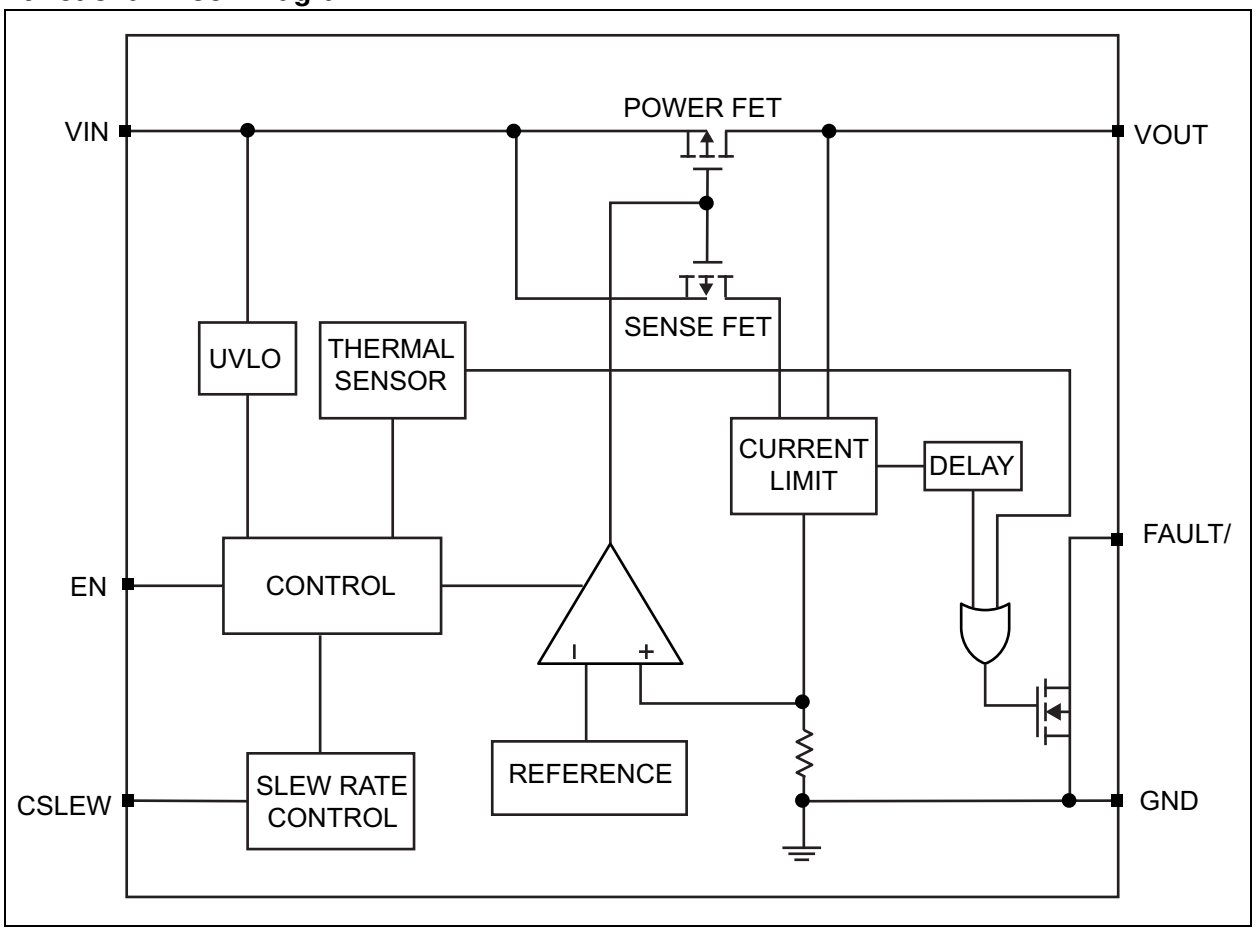
Note 1: Thin DFN ▲ = Pin 1 identifier.

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Typical Application Circuit



Functional Block Diagram



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1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

V_{IN} to GND ..... –0.3V to +6V
V_{OUT} to GND ..... –0.3V to V_{IN}
V_{CSLEW} to GND ..... –0.3V to V_{IN} + 0.3V
V_{EN} to GND ..... –0.3V to +6V
$V_{FAULT/}$ to GND ..... –0.3V to V_{IN} + 0.3V
FAULT/ Current ($I_{FAULT/}$) ..... 25 mA
Maximum Power Dissipation (P_D) ..... Internally Limited
ESD Rating (HBM) (Note 1) ..... 3 kV
ESD Rating (MM) (Note 1) 300V

Operating Ratings ‡

Supply Voltage (V_{IN}) ..... +2.5V to +5.5V
V_{EN} ..... –0.3V to +5.5V
V_{CSLEW}, V_{OUT} ..... –0.3V to V_{IN}

† Notice: Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

‡ Notice: The device is not guaranteed to function outside its operating ratings.

Note 1: Devices are ESD sensitive. Handling precautions are recommended. Human body model, 1.5 kΩ in series with 100 pF.

TABLE 1-1: ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{IN} = V_{EN} = 5V, C_{IN} = 1 µF, C_{CSLEW} = OPEN, C_{OUT} = 1 µF; T_J = +25°C, unless noted. **Bold** values indicate –40°C ≤ T_J ≤ +125°C. **(Note 1)**.

Symbol	Parameters	Min.	Typ.	Max.	Units	Conditions
Power Supply Input						
V_{IN}	Input Voltage Range	**2.5**	—	**5.5**	V	—
V_{UVLO}	Input Supply Undervoltage Lockout Threshold	**2.0**	2.25	**2.5**	V	V_{IN} rising
		1.9	2.15	**2.4**		V_{IN} falling
$V_{UVLOHYS}$	Input Supply Undervoltage Lockout Threshold Hysteresis	—	100	—	mV	V_{IN} rising or V_{IN} falling
I_{DD}	Supply Current	—	0.75	**5**	µA	Switch OFF; Active-High Enable (A): V_{EN} = 0V, V_{IN} = 5V, I_{OUT} = 0A
						Switch OFF; Active-Low Enable (B): V_{EN} = V_{IN} = 5V, I_{OUT} = 0A
		—	100	**300**	µA	Switch ON; Active-High Enable (A): V_{EN} = 1.5V, V_{IN} = 5V, I_{OUT} = 0A
						Switch ON; Active-Low Enable (B): V_{EN} = 0V, V_{IN} = 5V, I_{OUT} = 0A
Power MOSFET						
$R_{DS(ON)}$	Switch On-Resistance	—	100	**177**	mΩ	V_{IN} = 2.5V, I_{OUT} = 350 mA
		—	85	**145**		V_{IN} = 3.3V, I_{OUT} = 350 mA
		—	75	**125**		V_{IN} = 5V, I_{OUT} = 350 mA
I_{LKG}	Output Leakage Current		0.22	**15**	µA	Switch OFF, V_{OUT} = 0V
Current-Limit						
I_{LIMIT}	Current-Limit Accuracy	0.475	0.5	0.525	A	MIC2033-05xxxx, V_{OUT} = 0.8*V_{IN}
		0.76	0.8	0.84		MIC2033-08xxxx, V_{OUT} = 0.8*V_{IN}
		0.95	1.0	1.05		MIC2033-10xxxx, V_{OUT} = 0.8*V_{IN}
		1.14	1.2	1.26		MIC2033-12xxxx, V_{OUT} = 0.8*V_{IN}
I/O						
V_{EN}	Enable Voltage	—	—	**0.5**	V	Logic-Low
		1.5	—	—		Logic-High
I_{EN}	Enable Input Current	—	1	—	µA	0V ≤ V_{EN} ≤ 5V
R_{FLAG}	Fault Flag Output Resistance	—	—	**25**	Ω	I_{OUT} = 10 mA

Note 1: Specification for packaged product only.

2: See Timing Diagrams.

3: C_{CSLEW} values above 0.1 µF are not recommended.

4: For dynamic current loads faster than typically 30 mA/ms. Slower current loads will delay the deactivation of VOUT and the current limitation, allowing FAULT/ to be asserted before these.

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TABLE 1-1: ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: $V_{IN} = V_{EN} = 5V$, $C_{IN} = 1\ \mu F$, C_{CSLEW} = OPEN, $C_{OUT} = 1\ \mu F$; $T_J = +25°C$, unless noted. **Bold** values indicate $–40°C \le T_J \le +125°C$. (**Note 1**).

Symbol	Parameters	Min.	Typ.	Max.	Units	Conditions
I_{FLAG_OFF}	Fault Flag Off Current	—	—	10	µA	$V_{FLAG} = V_{IN}$
$R_{FAULT/}$	FAULT/ Output Resistance	—	—	**25**	Ω	I_{OUT} = 10 mA
$I_{FAULT/_OFF}$	FAULT/ Off Current	—	—	10	µA	$V_{FAULT/} = V_{IN}$
I_{CSLEW}	CSLEW Input Current (Note 2)	—	0.6	—	µA	$V_{CSLEW} = V_{IN}$
Thermal Protection						
T_{TSD}	Thermal Shutdown Temperature	—	157	—	°C	T_J rising
T_{TSDHYS}	Thermal Shutdown Hysteresis	—	15	—	°C	—
Timing Specifications (AC Parameters)						
t_{RISE}	Output Turn-on Rise Time (Note 2)	—	700	—	µs	R_{LOAD} = 10Ω; $C_{OUT} = 1\ \mu F$
t_{FALL}	Output Turn-off Fall Time (Note 2)	—	32	—	µs	V_{EN} = OFF; R_{LOAD} = 10Ω; $C_{OUT} = 1\ \mu F$
t_{ON_DLY}	Output Turn-on Delay (Note 2)	—	700	—	µs	R_{LOAD} = 10Ω; $C_{OUT} = 1\ \mu F$
t_{OFF_DLY}	Output Turn-off Delay (Note 2)	—	5	—	µs	R_{LOAD} = 10Ω; $C_{OUT} = 1\ \mu F$
t_{SC_RESP}	Short Circuit Response Time (Note 2, Note 3)	—	10	—	ms	V_{OUT} = 0V (short-circuit); $C_{CSLEW} = 0.1\ \mu F$
t_{SC_RESP}	Short Circuit Response Time (Note 2)	—	10	—	µs	V_{OUT} = 0V (short-circuit); C_{CSLEW} = OPEN
$t_{FAULT/}$	Overcurrent Fault Response Delay Time (Note 2, Note 4)	**16**	32	**49**	ms	—

Note 1: Specification for packaged product only.

2: See Timing Diagrams.

3: C_{CSLEW} values above 0.1 µF are not recommended.

4: For dynamic current loads faster than typically 30 mA/ms. Slower current loads will delay the deactivation of VOUT and the current limitation, allowing FAULT/ to be asserted before these.

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TEMPERATURE SPECIFICATIONS

Parameters	Sym.	Min.	Typ.	Max.	Units	Conditions
Temperature Ranges						
Junction Operating Temperature Range	T_J	–40	—	+125	°C	Note 1
Storage Temperature Range	T_S	–65	—	+150	°C	—
Lead Temperature	—	—	—	+260	°C	Soldering, 10s
Package Thermal Resistances						
Thermal Resistance SOT-23-6	θ_{JA}	—	177.2	—	°C/W	—
Thermal Resistance 6-pin 2 mm x 2 mm DFN	θ_{JA}	—	90	—	°C/W	—

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +125°C rating. Sustained junction temperatures above +125°C can impact the device reliability.

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2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

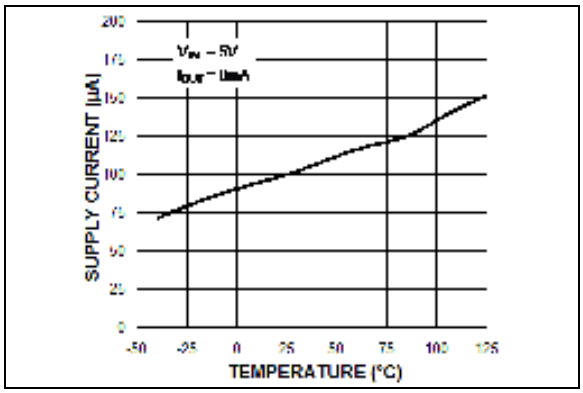


FIGURE 2-1: *Input Supply Current vs. Temperature.*

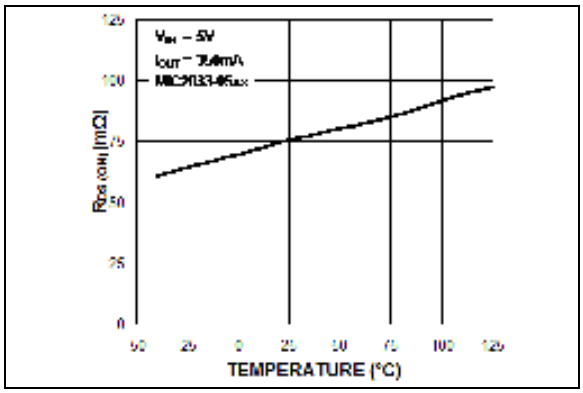


FIGURE 2-4: *$R_{DS(ON)}$ vs. Temperature.*

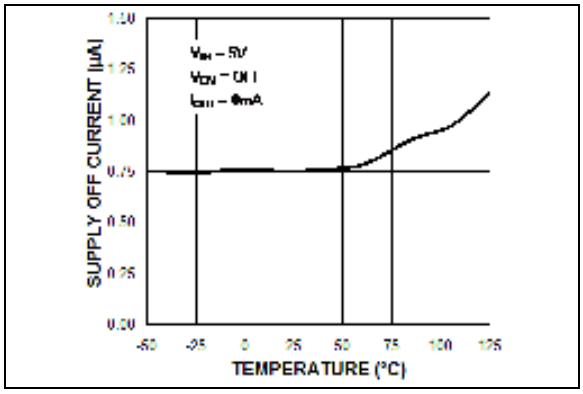


FIGURE 2-2: *V_{IN} OFF Current vs. Temperature.*

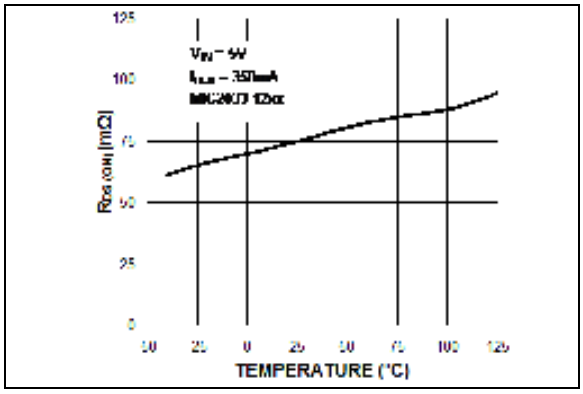


FIGURE 2-5: *$R_{DS(ON)}$ vs. Temperature.*

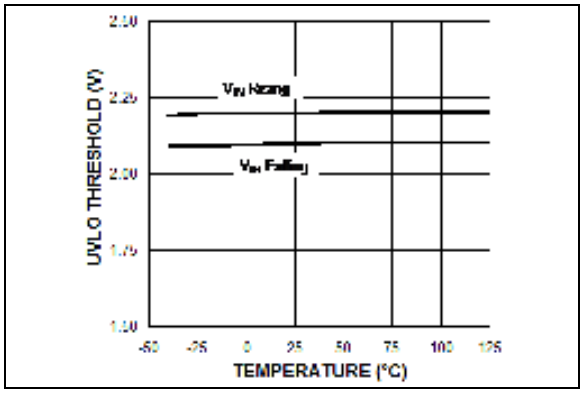


FIGURE 2-3: *Undervoltage Lockout vs. Temperature.*

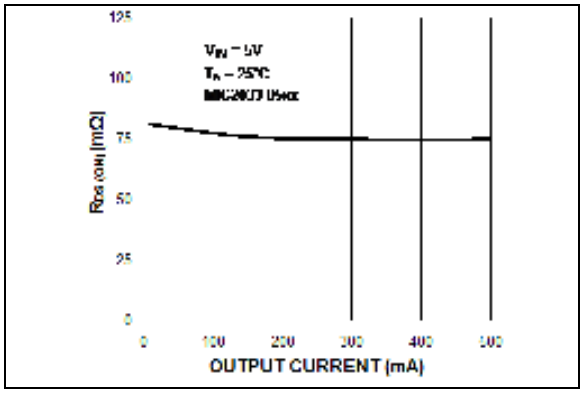


FIGURE 2-6: *$R_{DS(ON)}$ vs. Output Current.*

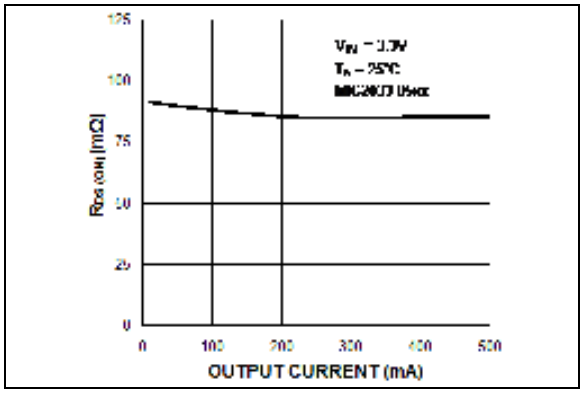


FIGURE 2-7: *$R_{DS(ON)}$ vs. Output Current.*

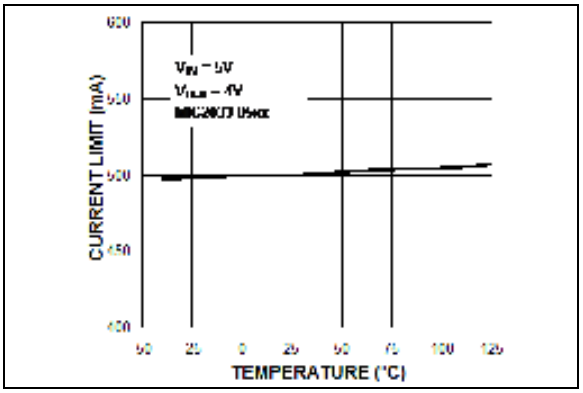


FIGURE 2-10: *Current Limit vs. Temperature.*

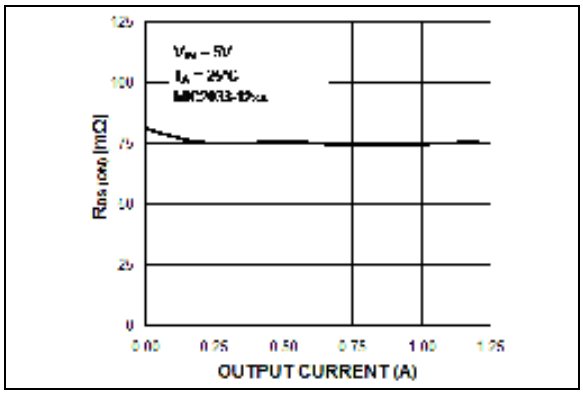


FIGURE 2-8: *$R_{DS(ON)}$ vs. Output Current.*

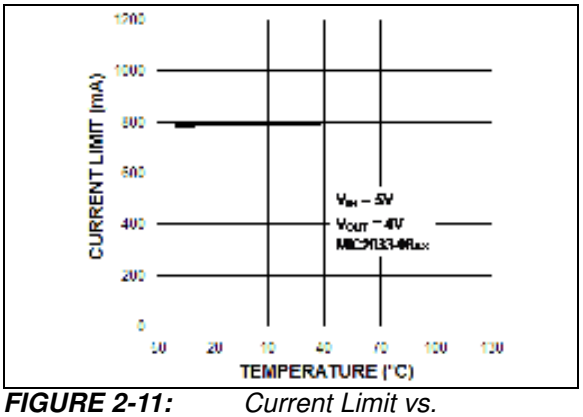


FIGURE 2-11: *Current Limit vs. Temperature.*

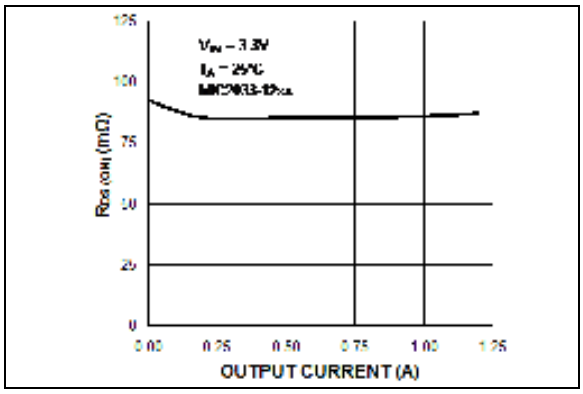


FIGURE 2-9: *$R_{DS(ON)}$ vs. Output Current.*

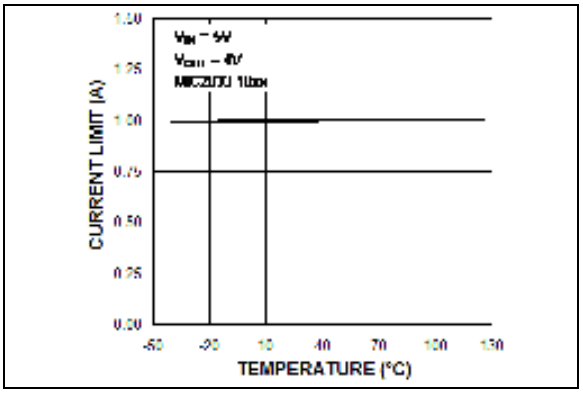


FIGURE 2-12: *Current Limit vs. Temperature.*

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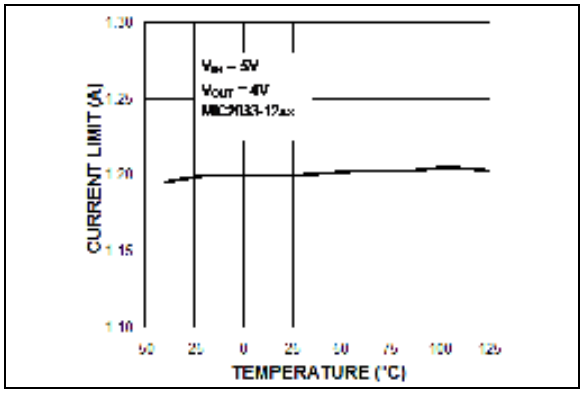


FIGURE 2-13: *Current Limit vs. Temperature.*

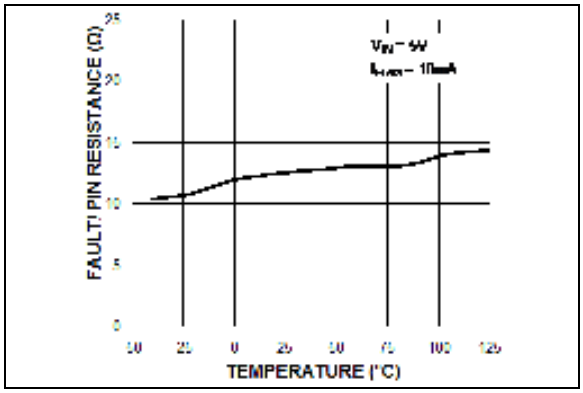


FIGURE 2-16: *FAULT/ Pin Resistance vs. Temperature.*

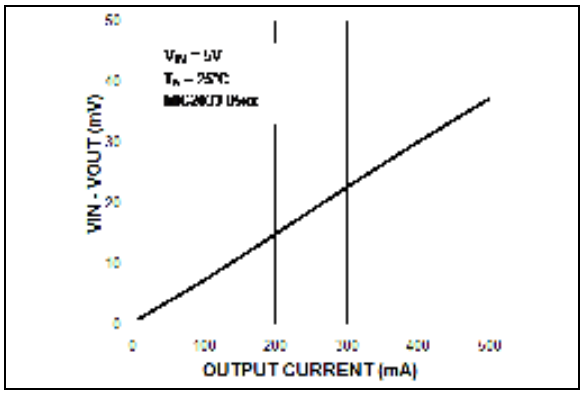


FIGURE 2-14: *V_{IN} - V_{OUT} vs. Output Current.*

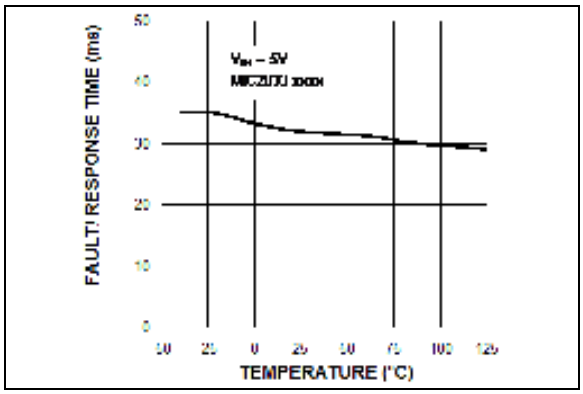


FIGURE 2-17: *FAULT/ Response Time vs. Temperature.*

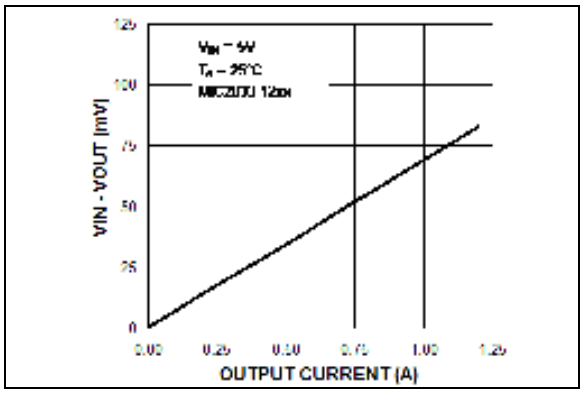


FIGURE 2-15: *V_{IN} - V_{OUT} vs. Output Current.*

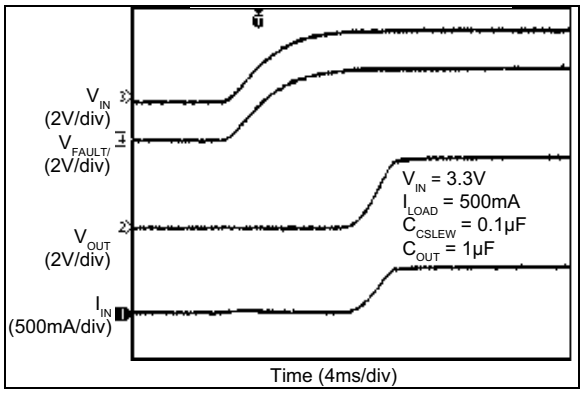


FIGURE 2-18: *Soft-Start Turn-On.*

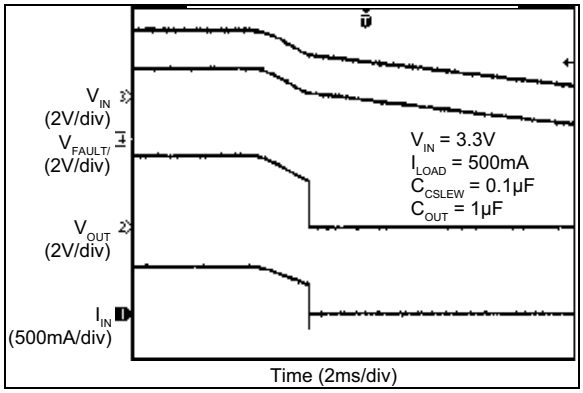


FIGURE 2-19: *Soft-Start Turn-Off.*

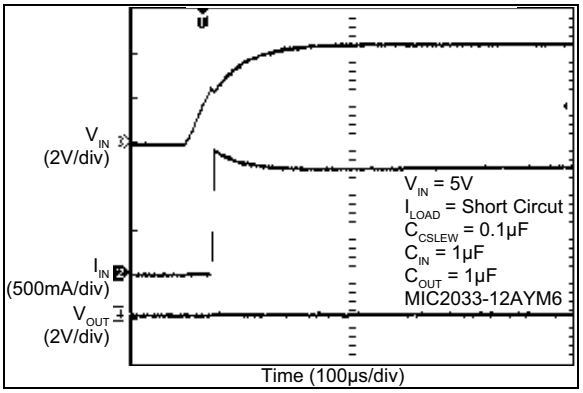


FIGURE 2-22: *Turn-On into Short-Circuit.*

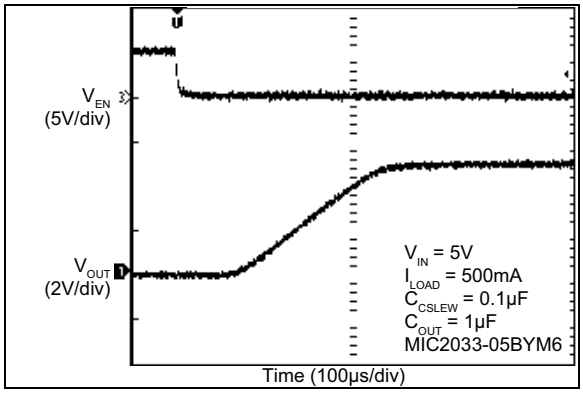


FIGURE 2-20: *Enable Turn-On.*

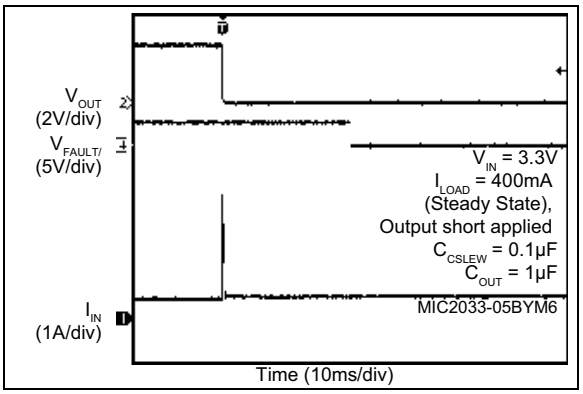


FIGURE 2-23: *Current-Limit Response, 400 mA Steady State Load.*

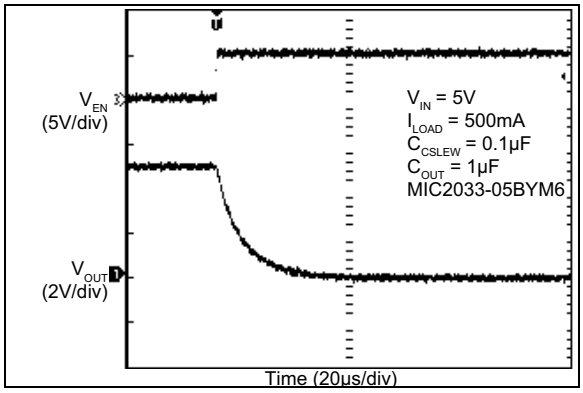


FIGURE 2-21: *Enable Turn-Off.*

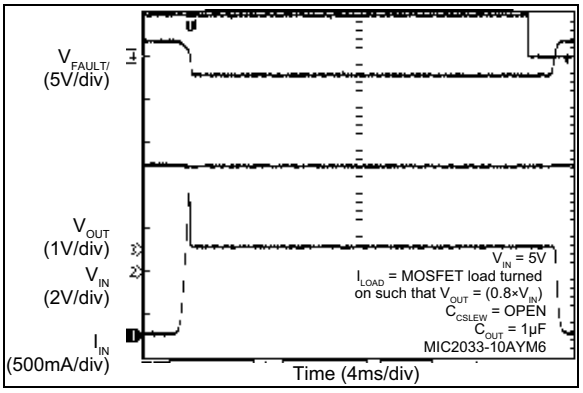


FIGURE 2-24: *Current-Limit Response.*

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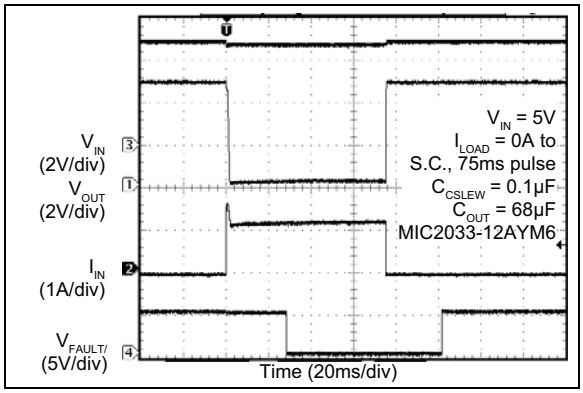


FIGURE 2-25: *Output Recovery from Short-Circuit.*

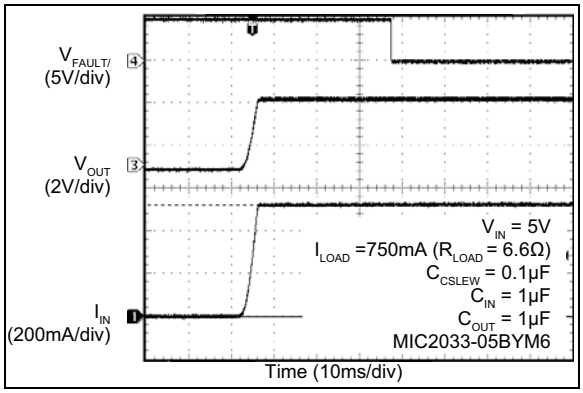


FIGURE 2-28: *Turn-On into 50% Overload.*

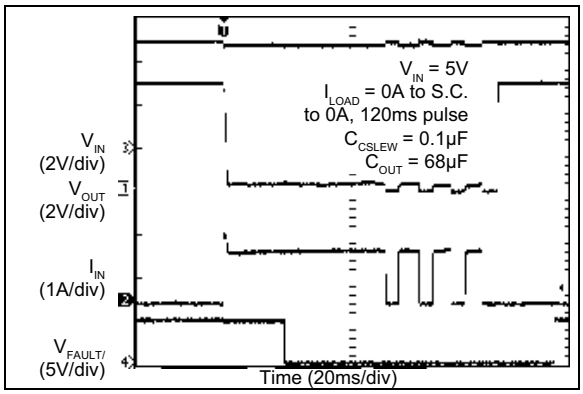


FIGURE 2-26: *V_{OUT} Recovery from Thermal Shutdown.*

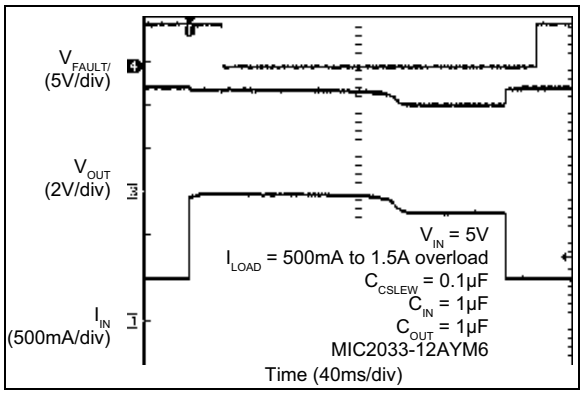


FIGURE 2-29: *1.5A Overload Response.*

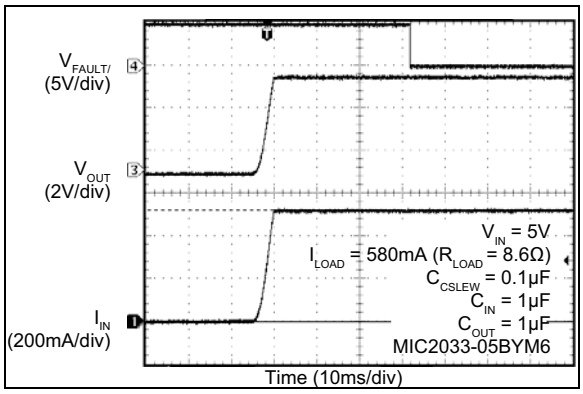


FIGURE 2-27: *Turn-On into Minimal Overload.*

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

Pin Number SOT-23-6L	Pin Number Thin DFN	Pin Name	Description
1	6	V_{IN}	Input: Power switch and logic supply input.
2	5	GND	Ground: Input and output return pin.
3	4	EN	Enable (Input): Logic compatible, enable control input that allows turn-on/off of the switch. Do not leave the EN pin floating.
4	3	FAULT/	Fault Status Flag (Output): Active-low, open-drain output. A logic-low state indicates an overcurrent or thermal shutdown condition. An overcurrent condition must last longer than $t_{FAULT/}$ in order to assert FAULT/. A pull-up resistor (10 kΩ recommended) to an external supply is required.
5	2	CSLEW	Slew Rate Control: Adjustable soft-start input. Adding a small value capacitor from CSLEW to V_{IN} slows the turn-on time of the power MOSFET.
6	1	V_{OUT}	Switch Output: Power switch output.
—	EP	ePad	Exposed Pad: Exposed pad on bottom side of package. Connect to electrical ground for optimum thermal dissipation.

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4.0 FUNCTIONAL DESCRIPTION

The MIC2033 is a high-side MOSFET power distribution switch providing increased system reliability utilizing 5% current-limit accuracy. The MIC2033 has an operating input voltage range from 2.5V to 5.5V and is internally current-limited and has thermal shutdown that protects the device and system.

4.1 Soft-Start

Soft-start reduces the power supply input surge current at startup by controlling the output voltage rise time. The input surge appears while the output capacitor is charged up. A slower output rise time will draw a lower input surge current.

During soft-start, an internal current sink discharges the external capacitor at CSLEW to ground to control the ramp of the output voltage. The output voltage rise time is dependent upon the value of C_{CSLEW}, the input voltage, output voltage, and the current limit. The value of the CSLEW external capacitor is recommended to be 0.1 µF.

4.2 Input Capacitor

A 1 µF to 100 µF ceramic input capacitor is recommended for most applications. The input capacitor must be placed on the same side of the board and next to the MIC2033 to minimize the voltage ringing during transient and short circuit conditions. It is also recommended to use two vias for each end of the capacitor to connect to the power and ground plane.

X7R or X5R dielectric ceramic capacitors are recommended because of their temperature performance. X7R-type capacitors change capacitance by 15% over their operating temperature range and are the most stable type of ceramic capacitors. Z5U and Y5V dielectric capacitors change value by as much as 50% and 60% respectively over their operating temperature ranges. To use a ceramic chip capacitor with Y5V dielectric, the value must be much higher than an X7R ceramic or a tantalum capacitor to ensure the same capacitance value over the operating temperature range.

4.3 Output Capacitor

The output capacitor type and placement criteria are the same as the input capacitor.

The exact amount of capacitance depends upon the specific application. For example, USB applications will typically use 150 µF, whereas local consumers, such as microcontrollers, may require as little as 1 µF.

Care must be taken when choosing the output capacitance for inductive loads. Without sufficient capacitance or clamping devices, sudden disconnects or shorts on VOUT can result in stresses beyond the device's absolute maximum ratings, even for short cables, which will damage the device.

4.4 Enable

The MIC2033 offers either an active-high or active-low enable input (EN) that allows ON/OFF control of the switch output. The current through the device reduces to near zero when the device is shutdown, with only microamperes of leakage current. The EN input may be directly tied to V_{IN} or driven by a voltage that is equal to or less than V_{IN}, but do not leave this pin floating.

Care should be taken to ensure that the EN pin does not exceed V_{IN} by more than 500 mV at any time. This includes at power-up and during load transients. Whenever possible, it is recommended to tie EN to V_{IN} through a pull-up resistor and use an open-drain or open-collector device to change the state.

4.5 Current Limit

The MIC2033 is available with four fixed current-limit settings: 0.5A, 0.8A, 1A, and 1.2A. If the output current exceeds the set current limit, then the MIC2033 switch will enter constant current-limit mode. The maximum allowable current limit may be less than the full specified and/or expected current if the MIC2033 is not mounted on a circuit board with sufficiently low thermal resistance. The MIC2033 responds within 10 µs to short-circuits to limit the output current and also provides an output fault flag that will assert (low) for an overcurrent condition that lasts longer than 32 ms.

4.6 Thermal Design

To help reduce the thermal resistance, the ePad (underneath the IC) should be soldered to the PCB ground and the placement of thermal vias either underneath or near the ePad is highly recommended. Thermal design requires the following application-specific parameters:

- Maximum ambient temperature (T_A)
- Output current (I_{OUT})
- Input voltage (V_{IN})
- Current Limit (I_{LIMIT})

When the MIC2033 is in constant current-limit mode, it may exceed the overtemperature threshold. If this occurs, the overtemperature condition will shut down the MIC2033 switch and the fault status flag will go active (assert low). After the switch cools down, it will turn on again. The MIC2033 power dissipation can be maximized by either lowering the thermal resistance on the exposed pad (only the DFN package has an exposed pad) on the printed circuit board, or by limiting the maximum allowable ambient temperature.

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4.7 Thermal Measurements

It is always wise to measure the IC's case temperature to make sure that it is within its operating limits. Although this might seem like a very elementary task, it is very easy to get erroneous results. The most common mistake is to use the standard thermal couple that comes with the thermal voltage meter. This thermal couple wire gauge is large, typically 22 gauge, and behaves like a heatsink, resulting in a lower case measurement.

There are two suggested methods for measuring the IC case temperature: a thermal couple or an infrared thermometer. If a thermal couple is used, it must be constructed of 36 gauge wire or higher to minimize the wire heatsinking effect. In addition, the thermal couple tip must be covered in either thermal grease or thermal glue to make sure that the thermal couple junction is making good contact to the case of the IC. This thermal couple from Omega (5SC-TT-K-36-36) is adequate for most applications.

To avoid this messy thermal couple grease or glue, an infrared thermometer is recommended. Most infrared thermometers' spot size is too large for an accurate reading on small form factor ICs. However, an IR thermometer from Optris has a 1 mm spot size, which makes it ideal for the 2 mm x 2 mm DFN package. Also, get the optional stand. The stand makes it easy to hold the beam on the IC for long periods of time.

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5.0 TIMING DIAGRAMS

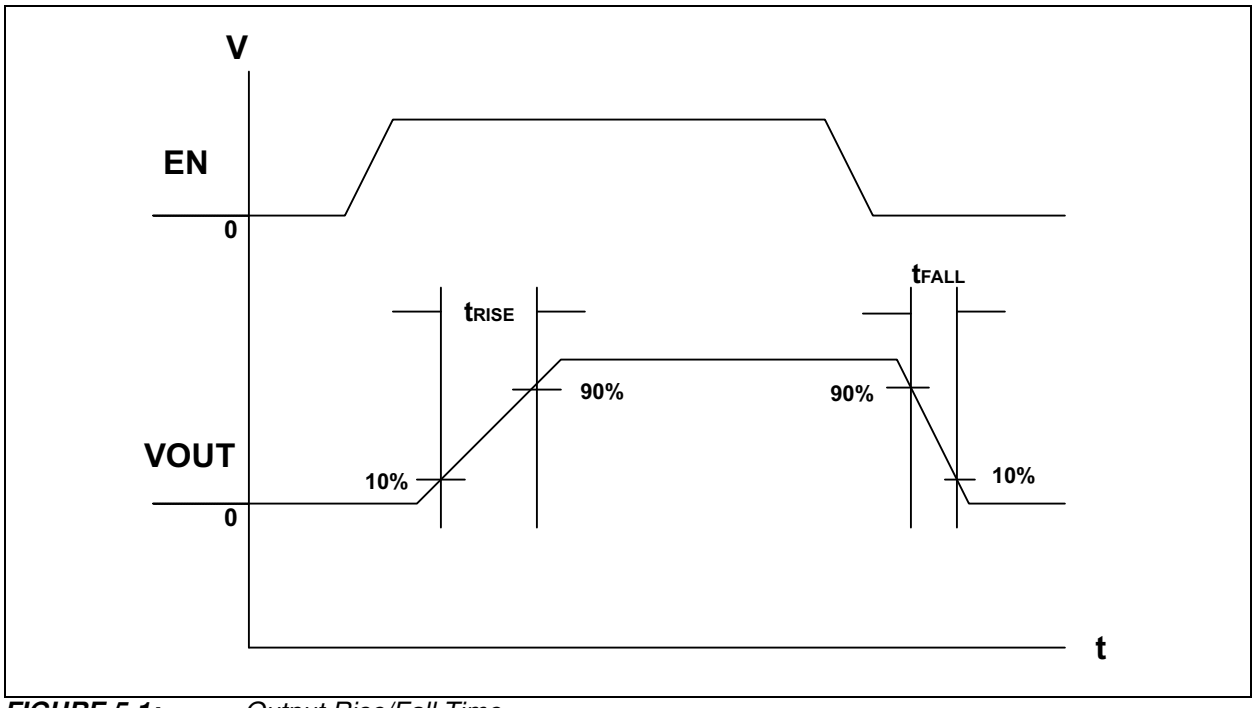


FIGURE 5-1: *Output Rise/Fall Time.*

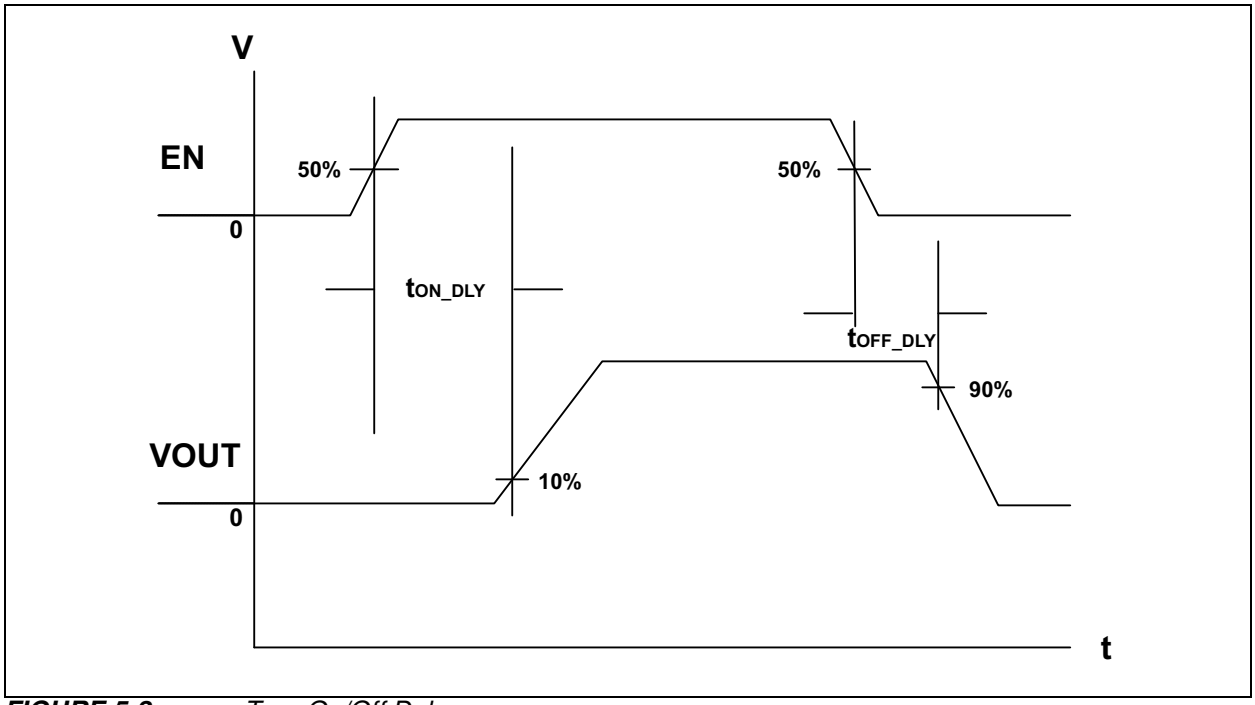


FIGURE 5-2: *Turn-On/Off Delay.*

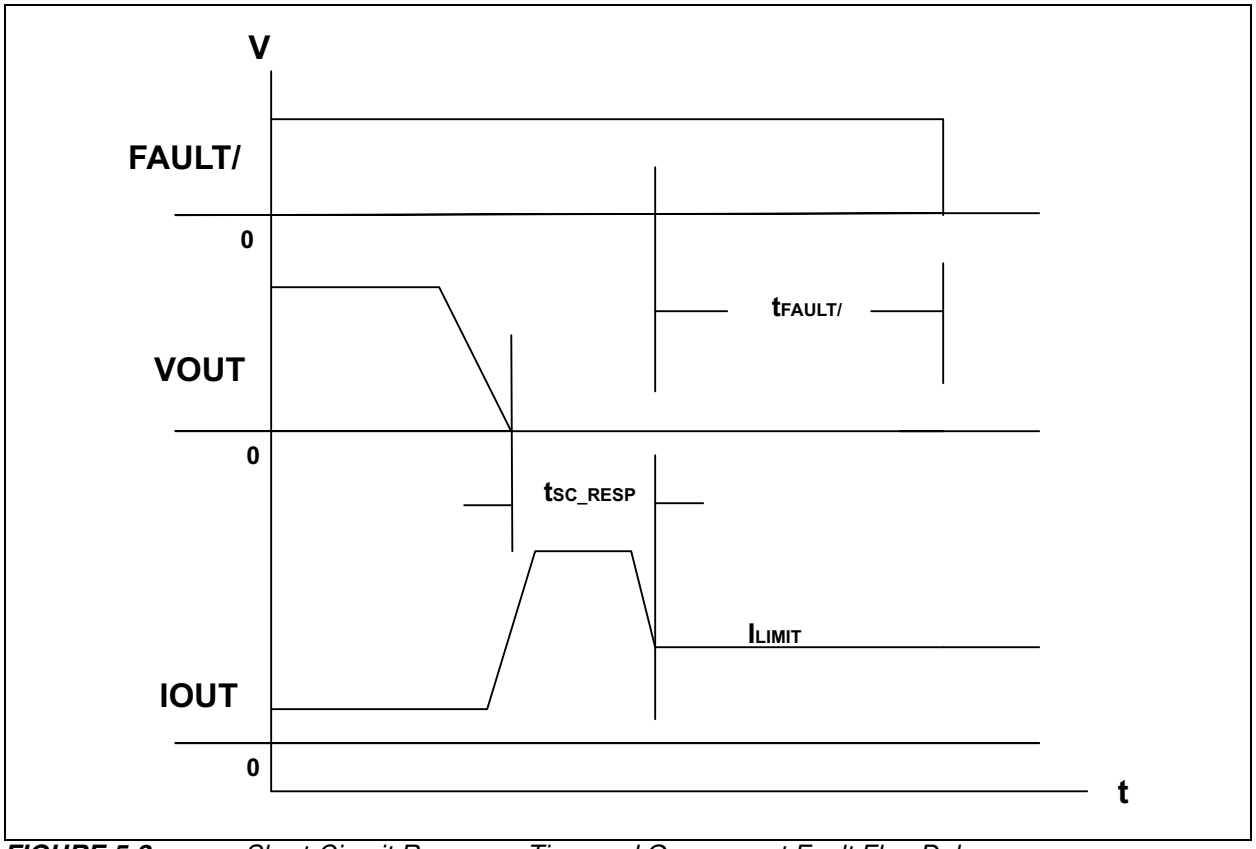


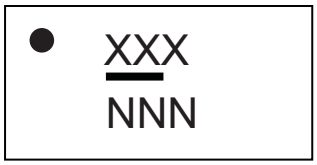
FIGURE 5-3: *Short-Circuit Response Time and Overcurrent Fault Flag Delay.*

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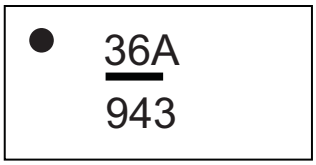
6.0 PACKAGING INFORMATION

6.1 Package Marking Information

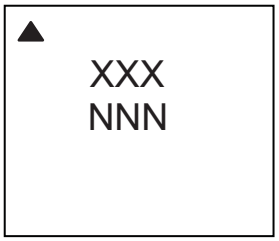
6-Pin SOT-23*



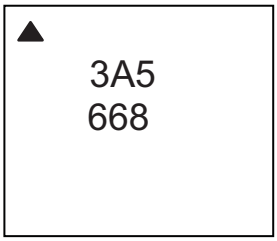
Example



6-Pin TDFN*



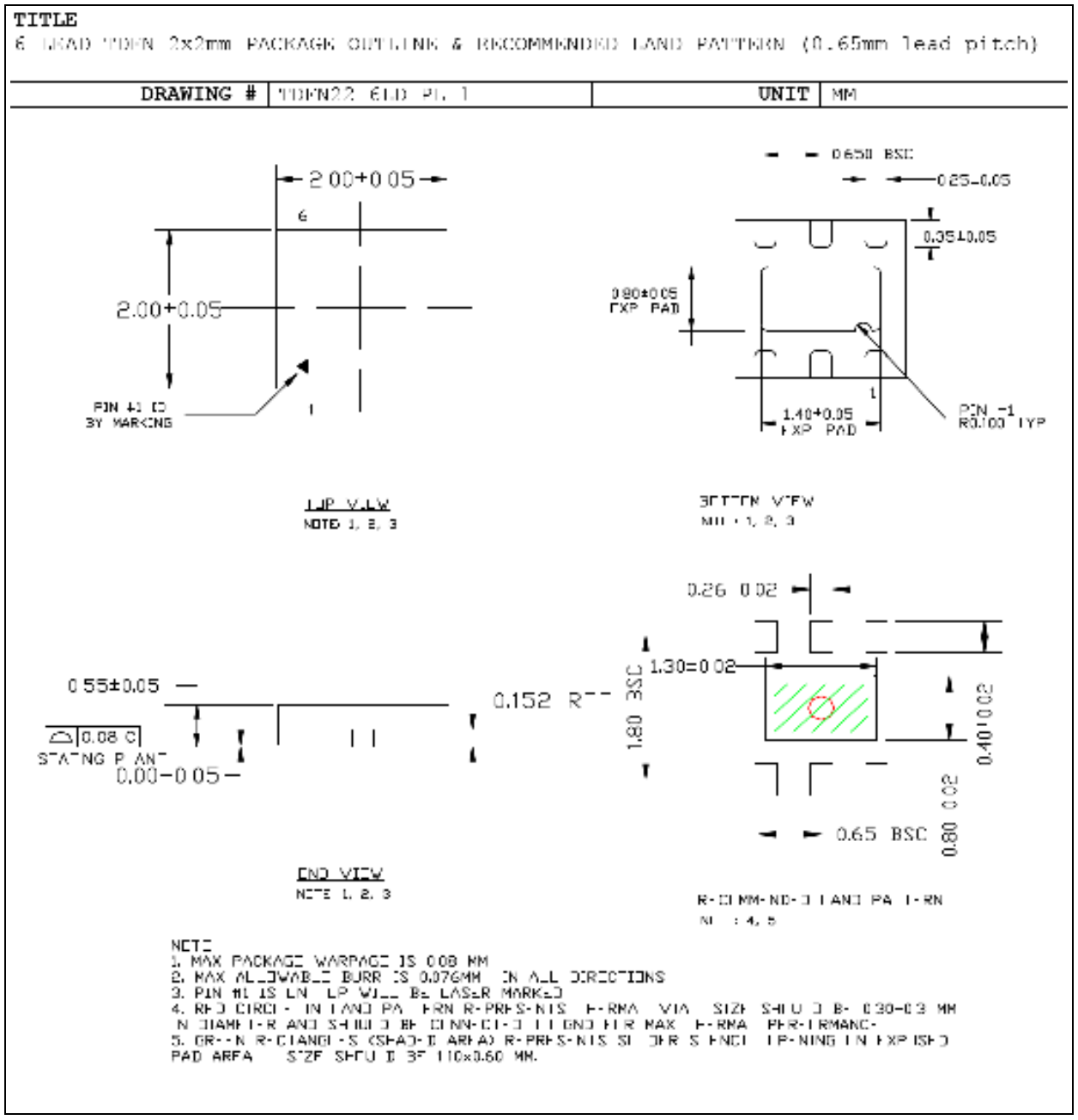
Example



Legend:	XX...X	Product code or customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week ‘01’)
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC® designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.
	●, ▲, ▼	Pin one index is identified by a dot, delta up, or delta down (triangle mark).
Note:	In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo.	
	Underbar (_) and/or Overbar (¯) symbol may not be to scale.	

6-Lead TDFN 2 mm x 2 mm Package Outline and Recommended Land Pattern

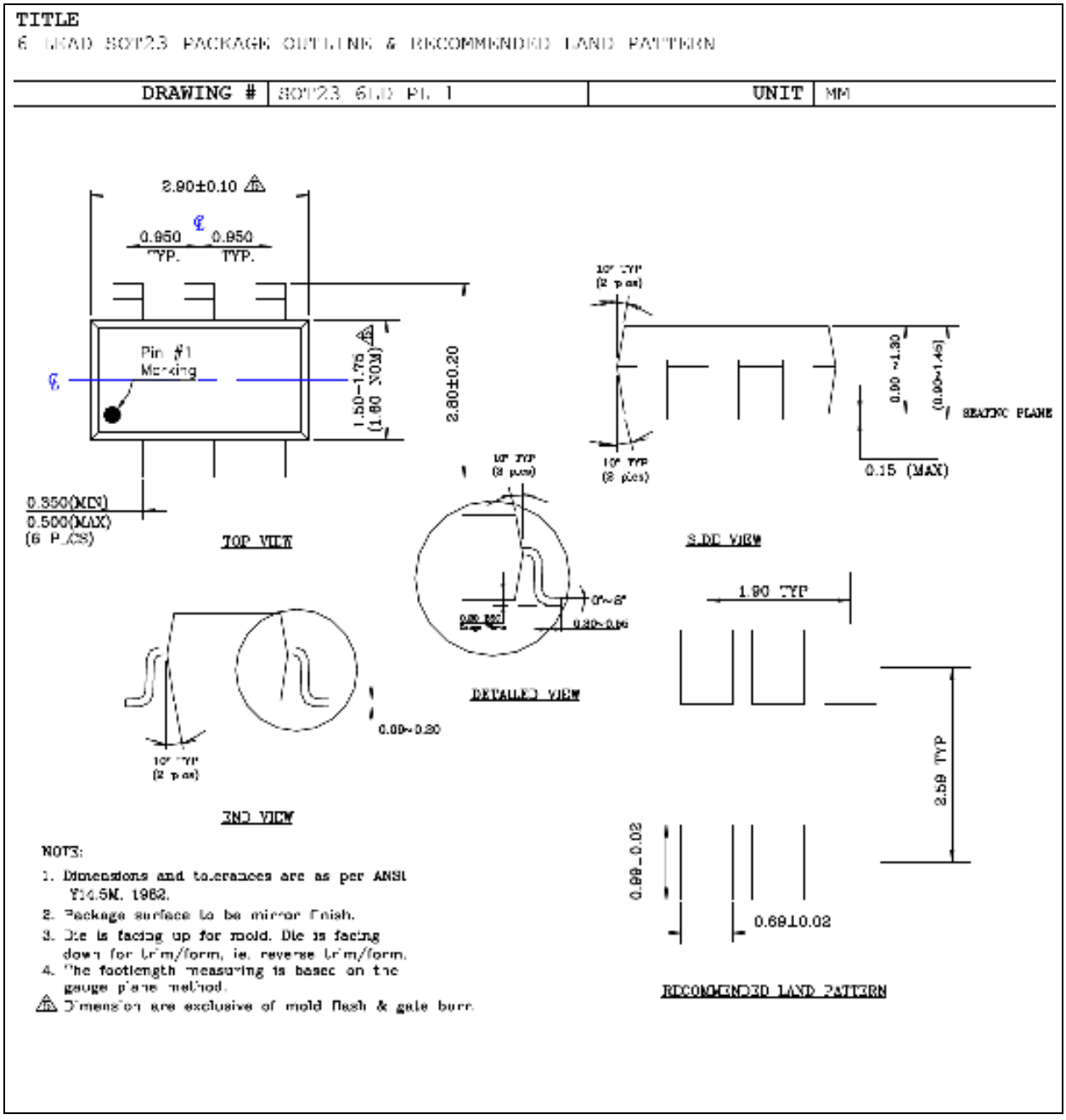
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



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6-Lead SOT-23 Package Outline and Recommended Land Pattern

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NOTES:

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APPENDIX A: REVISION HISTORY

Revision A (March 2018)

- Converted Micrel document MIC2033 to Microchip data sheet DS20005539A.
- Minor text changes throughout.
- Value of C1 updated in Typical Application Circuit.
- Maximum value of input capacitor corrected in Input Capacitor section.
- V_{EN} to GND corrected maximum value in Absolute Maximum Ratings †.
- V_{EN} and $V_{FAULT/}$ combined in Operating Ratings ‡.
- C_{CSLEW} value corrected to OPEN in Figure 2-24.
- CSLEW external capacitor value in the Soft-Start section corrected to 0.1 µF.

NOTES:

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PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

PART NO.	–	XX	X	X	XX	–	XX
Device		Current Limit	Enable	Temperature	Package		Media Type

Device:	MIC2033:		High-Accuracy, High-Side, Fixed Current-Limit Power Switch
Current Limit:	05	=	0.5A
	55	=	0.55A
	08	=	0.8A
	10	=	1.0A
	12	=	1.2A
Enable:	A	=	Active-High
	B	=	Active-Low
Temperature:	Y	=	–40°C to +125°C
Package:	M6	=	SOT-23-6L
	MT	=	6-Lead 2 mm x 2 mm TDFN (Note 1)
Media Type:	T5	=	500/Reel
	TR	=	3,000/Reel

Note 1: Thin DFN is a GREEN RoHS-compliant package. Lead finish is NiPdAu. Mold compound is Halogen Free.

Examples:

a) MIC2033-05AYM6-T5: High-Accuracy, High-Side, Fixed Current-Limit Power Switch, 0.5A Current Limit, Active-High Enable, –40°C to +125°C Temp. Range, SOT-23-6L Package, 500/Reel

b) MIC2033-55AYMT-TR: High-Accuracy, High-Side, Fixed Current-Limit Power Switch, 0.55A Current Limit Active-High Enable, –40°C to +125°C Temp. Range, 6-Pin 2 mm x 2 mm TDFN Package, 3,000/Reel

c) MIC2033-08BYM6-TR: High-Accuracy, High-Side, Fixed Current-Limit Power Switch, 0.8A Current Limit, Active-Low Enable, –40°C to +125°C Temp. Range, SOT-23-6L Package, 3,000/Reel

d) MIC2033-10BYMT-T5: High-Accuracy, High-Side, Fixed Current-Limit Power Switch, 1.0A Current Limit Active-Low Enable, –40°C to +125°C Temp. Range, 6-Pin 2 mm x 2 mm TDFN Package, 500/Reel

e) MIC2033-12AYM6-T5: High-Accuracy, High-Side, Fixed Current-Limit Power Switch, 1.2A Current Limit, Active-High Enable, –40°C to +125°C Temp. Range, SOT-23-6L Package, 500/Reel

f) MIC2033-12BYMT-TR: High-Accuracy, High-Side, Fixed Current-Limit Power Switch, 1.2A Current Limit Active-Low Enable, –40°C to +125°C Temp. Range, 6-Pin 2 mm x 2 mm TDFN Package, 3,000/Reel

Note 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.

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